

## SOLID STATE - 2

### Density, Bragg's Equation, Crystal Defects and Properties of solids

1) Density of a crystal is given by:

$$1) \frac{a^3 \times M}{z \times N_o} \quad 2) \frac{z \times M}{a^3 \times N_o} \quad 3) \frac{N_o \times M}{z \times a^3} \quad 4) \frac{a^3 \times N_o}{z \times M}$$

2) An element crystallizes in a structure having F.C.C. unit cell of an edge 200 pm.

Calculate the density if 200 gm of it contains  $24 \times 10^{23}$  atoms

$$1) 41.6 \text{ gm/cm}^3 \quad 2) 42.6 \text{ gm/cm}^3 \quad 3) 43.6 \text{ gm/cm}^3 \quad 4) 44.6 \text{ gm/cm}^3$$

HINT: Mass of  $24 \times 10^{23}$  atoms = 200 gm, Mass of  $6 \times 10^{23}$  atoms (M) = 50 gm

$$\rho = \frac{ZM}{N_o \cdot a^3} = \frac{4 \times 50}{6 \times 10^{23} \times (200 \times 10^{-10})^3} = 41.6 \text{ gm/cm}^3$$

3) A metal crystallizes in two cubic phases, fcc and bcc whose unit cell lengths are  $2^0 \text{ \AA}$  and  $3^0 \text{ \AA}$  respectively. The ratio of density of fcc and bcc is

$$1) 1.5 \quad 2) 3.375 \quad 3) 13.5 \quad 4) 6.75$$

$$\text{Hint: } \frac{\rho_1}{\rho_2} = \frac{z_1}{z_2} \cdot \frac{(a_2)^3}{(a_1)^3} = \frac{4}{2} \times \frac{3^3}{2^3} = 6.75$$

4) Ice crystallizes in a hexagonal lattice having volume of the unit cell as  $132 \times 10^{-24} \text{ cm}^3$ . If density is 0.92 g at a given temperature, then number of  $\text{H}_2\text{O}$  molecules per unit cell is

$$1) 1 \quad 2) 2 \quad 3) 3 \quad 4) 4$$

$$\text{Hint: } z = \frac{\rho \cdot N_o \cdot V}{M} = \frac{132 \times 10^{-24} \times 6 \times 10^{23} \times 0.92}{18} = 4$$

5) A metal crystallizes as body centered cubic lattice with the edge length of unit cell equal to 0.304 nm. If the molar mass of the metal is  $50.3 \text{ g mol}^{-1}$ , its density is

$$1) 5.945 \text{ g cm}^{-3} \quad 2) 2.9725 \text{ g cm}^{-3}$$

$$3) 8.9175 \text{ g cm}^{-3} \quad 4) 4.458 \text{ g cm}^{-3}$$

$$\text{Hint: } \rho = \frac{ZM}{N_o \cdot a^3}, \text{ here } z = 2, a = 0.304 \times 10^{-7} \text{ cm}$$

6) A element 'X' crystallizes as face centered cubic lattice with edge length of 460 pm. The density of the element X, when molar mass of X atom is 60 gm/mol is

- 1) 4.096 gm/mol    2) 2.048 gm/mol    3) 6.144 gm/mol    4) 3.072 gm/mol

Hint:  $\rho = \frac{ZM}{N_0 \cdot a^3}$ , here  $z=4$ ,  $a=460 \times 10^{-10} = 4.6 \times 10^{-8}$

7) If the density of NaCl = 2.165 g cm<sup>-3</sup> and the distance between Na<sup>+</sup> and Cl<sup>-</sup> = 281 pm, Avogadro's number is equal to

- 1)  $7 \times 10^{23} \text{ mol}^{-1}$     2)  $8 \times 10^{23} \text{ mol}^{-1}$     3)  $6 \times 10^{23} \text{ mol}^{-1}$     4)  $3 \times 10^{23} \text{ mol}^{-1}$

8) The ratio of 'd' values in NaCl crystal is

- 1) 0.703:1:1.134    2) 1:1.34:0:703    3) 1:0.703:1.134    4) 0.703:1.134:1

9) The second order Bragg diffraction of X-rays with  $\lambda = 1.00 \text{ \AA}$  from a set of parallel planes in a metal occurs at an angle of 60°. The distance between the scattering planes in the crystal is

- 1) 0.575 Å    2) 1.00 Å    3) 2.00 Å    4) 1.15 Å

Hint:  $n\lambda = 2d \sin \theta$ ,  $d = 2X/2X \sin 60 = 1/\sin 60 = 2/\sqrt{3} = 1.15$

10) From Bragg's equation which one of the following is wrong?

- 1) Incident angle value is in between 0 to 90°  
2) Order of diffraction 'n' is an integer  
3)  $2d < n\lambda$   
4) As  $\lambda$  of x-rays increases, incident angle for first order diffraction increases

11) At what angle for a first order diffraction, the distance between two adjacent planes of crystal is equal to the wavelength of X-rays used

- 1) 45°    2) 30°    3) 90°    4) 60°

HINT: AS  $d = \lambda$ ,  $\sin \theta = 1/2$  i.e.  $\theta = 30$

12) If two waves with the amplitude 'a' of each undergo constructive interference, the amplitude of the resulting wave is

- 1) 0    2) 2a    3) < 2 a    4) a<sup>2</sup>

13) Schottky defect causes

- 1) Increase in the density of solid  
2) Decrease in the density of solid  
3) No change in the density of solid  
4) Decrease in the conductivity of solid.

14) What type of crystal defect is indicated in the diagram below

- 1) Frenkel defect
- 2) Frenkel and Schottky defects
- 3) Interstitial defect
- 4) Schottky defect

15) Schottky - Wagner defects are mostly found in

- 1) Ionic compounds with high co-ordination number
- 2) Ionic compound with low co-ordination number
- 3) Covalent compounds with low coordination number
- 4) Covalent compound with high coordination number

16) Which among the following is likely to have Schottky defect?

- 1) Ag Cl      2) NaCl                      3) TiCl              4) MgCl<sub>2</sub>

17) A: During vacancy defect the density of solid decreases

R: The vacancies in the lattice lower the density of solid

18) Schottky defect in crystals is observed when

- 1) Unequal number of cations and anions are missing from the lattice
- 2) Equal number of cations and anions are missing from the lattice
- 3) An ion leaves its normal site and occupies an interstitial cells
- 4) Density of the crystal is increased

19) List - I

List - II

- A) Crystal defect      1) Amorphous
- B) Carborundum      2) Frenkel
- C) Pitch                  3) Covalent crystal

The correct match is

- |    | A | B | C |    | A | B | C |
|----|---|---|---|----|---|---|---|
| 1) | 3 | 1 | 2 | 2) | 2 | 1 | 3 |
| 3) | 2 | 3 | 1 | 4) | 1 | 2 | 3 |

20) Which of the following is a "Berthollide Compound"?

- 1) MgO      2) Al<sub>2</sub>O<sub>3</sub>      3) Na<sub>2</sub>O      4) ZrH<sub>2</sub>

21) The formula of an oxide of iron is  $Fe_{0.93}O_{1.00}$ . If the compound has hundred  $O^{2-}$  ions, then it contains

- 1)  $93Fe^{+2}$  ions   2)  $93Fe^{+3}$  ions   3)  $79Fe^{+2}, 14Fe^{+3}$    4)  $93Fe^{+2}, 14Fe^{+3}$

**Solution;** Let the sample contains 93 iron ions & 100 oxide ions

Total negative charge on oxide ions =  $100 \times -2 = -200$

No of  $Fe^{+3}$  ions = X

No of  $Fe^{+2}$  ions =  $93 - x$

Total positive charge =  $x(+3) + (93-x)(+2)$

Numerically +ve charge and -ve charge are equal

Thus  $3x + (93-x)2 = 200$

$x = 14$

22) To get n-type semiconductor, impurity to be added to silicon should have the following number of valence electrons

- 1) 2   2) 3   3) 1   4) 5

23) (A): With increase in temperature the conductivity of metals decreases.

(R): with increase in temperature lattice vibrations increases in metals.

24) The mechanism of electrical conductivity may be given in terms of

- 1) Vacancy mechanism  
2) Interstitial mechanism  
3) Interstitially mechanism  
4) All

25) A: Metals are generally good conductors of electricity

R: Electrical conductivity of metals is due to Schottky type defects

26). In which of the following the conductivity would be in the order of  $10^{-4} \text{ ohm}^{-1} \text{ cm}^{-1}$

- 1) NaCl(s)                      2) Na(s)  
3) Diamond                      4) Ge

27). Which one of the following ratio gives the purity of the metal (-resistivity (or) specific resistance)

- 1)  $\frac{\rho_{300^\circ C}}{\rho_{4.2^\circ C}}$     2)  $\frac{\rho_{300K}}{\rho_{4.2K}}$     3)  $\frac{\rho_{27K}}{\rho_{4K}}$     4)  $\frac{\rho_{300K}}{\rho_{4^\circ C}}$

28) Germanium can be made n-type semi conductor by doping with

- 1) silicon                      2) arsenic  
3) gallium                      4) either As (or) Ga

- 29) Which one of the following statements is wrong?
- 1) With increasing the temperature the electrical conductivity of Germanium decreases
  - 2) Silicon doped with phosphorus is n-type semi conductor
  - 3) Germanium doped with indium is p-type semi conductor
  - 4) Doping increases the conductivity of semi conductor
- 30) The magnetic susceptibility of a substance can be expressed as
- 1) gram susceptibility
  - 2) volume susceptibility
  - 3) molar susceptibility
  - 4) all
- 31) **A: Antiferromagnetic substances possess almost zero magnetic moment**  
**R: There are no unpaired electrons in antiferromagnetic substances**
- 32) Which of the following is correct statement?
- 1) silicon doped with boron is n-type semiconductor
  - 2) silicon doped with arsenic is a p-type semiconductor
  - 3) metals are good conductors of electricity
  - 4) electrical conductivity of semiconductors decreases with increasing temperature
- 33) The general formula of ferrites is  $MFe_2O_4$ . Where 'M' would not be
- 1) Mg
  - 2) Cu
  - 3) Al
  - 4) Zn
- 34) **A:  $K_4[Fe(CN)_6]$  is diamagnetic**  
**R: The alignments of magnetic dipoles are in compensatory to give zero magnetic moment**
- 35) Which substance shows anti ferro magnetism?
- 1)  $ZrO_2$
  - 2)  $CdO_3$
  - 3)  $CrO_2$
  - 4)  $V_2O_3$
- 36) **A:  $Fe_3O_4$  is ferromagnetic at room temperature but becomes paramagnetic at 850 K**  
**R: The magnetic moments in  $Fe_3O_4$  are aligned equally in parallel and antiparallel directions which on heating randomise**

37) The alignment of magnetic dipoles shown below represents which of the following?

↑ ↓ ↓ ↑ ↓ ↓

- 1) Diamagnetism
- 2) Ferri magnetism
- 3) Ferro magnetism
- 4) Anti-ferromagnetism

38) List - I                      List - II

A) Antiferromagnetic      1)  $ZnFe_2O_4$

B) Covalent crystal        2) NiO

C) Ferrimagnetic          3) Diamond

The correct match is

- |    | A | B | C |    | A | B | C |
|----|---|---|---|----|---|---|---|
| 1) | 2 | 3 | 1 | 2) | 3 | 2 | 1 |
| 3) | 1 | 2 | 3 | 4) | 1 | 3 | 2 |

39) Which one of the following is correct?

- 1) Schottky defect lowers the density
- 2) Frenkel defect increases the dielectric constant of the crystals
- 3) Stoichiometric defects make the crystals good electrical conductors
- 4) All of these

40) At zero Kelvin, most of the ionic crystals possess

- 1) No defect
- 2) Frenkel defect
- 3) Schottky defect
- 4) Metal excess defect

41) (A): Schottky and Frenkel defects are also called as 'thermodynamic defects'

(R): Both schottky and frenkel defects increases with increase in temperature

- 1) Both (A) and (R) are true and (R) is the correct explanation of (A)
- 2) Both (A) and (R) are true but (R) is not the correct explanation of (A)
- 3) (A) is true but (R) is false.
- 4) Both (A) and (R) are false.

42) **The electrical conductivity of semiconductors**

- 1) Increases with temperature
- 2) Decreases with temperature
- 3) Remains constant on heating
- 4) All the above

43) **Which substance will conduct the current in the solid state?**

- 1) Diamond
- 2) Graphite
- 3) Iodine
- 4) Sodium chloride

44) **To get p-type doped semiconductor, impurity to be added to silicon should have the following number of valence electrons**

- 1) 1
- 2) 2
- 3) 3
- 4) 5

45) **A diode is**

- 1) npn or pnp type of semi conductor
- 2) only n type of semi conductor
- 3) only p type of semi conductor
- 4) only npn type of semi conductor

46) **Ferromagnetism is maximum in**

- 1) Fe
- 2) Co
- 3) Ni
- 4) equal in all

47) **Assertion (A): Electrical conductivity of semiconductors increases with increasing temperature**

**Reason (R): With increase in temperature, large number of electrons from the valence band can jump to the conduction band.**

- 1) Both (A) and (R) are true and (R) is the correct explanation of (A)
- 2) Both (A) and (R) are true but (R) is not the correct explanation of (A)
- 3) (A) is true but (R) is false.
- 4) Both (A) and (R) are false.

48) **Assertion (A):  $Fe_3O_4$  is ferrimagnetic at room temperature but becomes paramagnetic at 850K**

**Reason (R): The magnetic moments in are aligned equally in parallel and antiparallel directions which on heating randomise**

- 1) Both (A) and (R) are true and (R) is the correct explanation of (A)
- 2) Both (A) and (R) are true but (R) is not the correct explanation of (A)
- 3) (A) is true but (R) is false.
- 4) Both (A) and (R) are false.

49) X-rays of wavelength equal to 1.134nm give a first order diffraction from the surface of a crystal when the value of  $\theta$  is  $10.5^\circ$ , then the distance between the adjacent plane in the crystal is ( $\sin 10.5^\circ = 0.1822$ )

- 1) 367nm                      2) 0.367nm  
3) 3.67nm                    4) 0.0367 nm

Hint;  $2d \sin \theta = n \lambda$

50) In a diffraction experiment, x-rays of wavelength 0.14nm were used on a crystal. 'n' is the order of diffraction that occurs at an angle of  $\theta$  is  $19.5^\circ$ . If the interplanar distance is 4.42nm n value is ( $\sin 19.5^\circ = 0.333$ )

- 1) 2    2) 1                    3) 3                    4) 4

Hint;  $2d \sin \theta = n \lambda$

### ANSWERS

- 1) 4    2) 2    3) 4    4) 4    5) 1    6) 1    7) 3    8) 3    9) 4    10) 3  
11) 2    12) 2    13) 2    14) 4    15) 1    16) 2    17) 1    18) 2    19) 3    20) 4  
21) 3    22) 4    23) 1    24) 4    25) 3    26) 4    27) 2    28) 2    29) 1    30) 4  
31) 3    32) 3    33) 3    34) 3    35) 4    36) 3    37) 2    38) 1    39) 4    40) 1  
41) 4    42) 1    43) 2    44) 3    45) 1    46) 1    47) 1    48) 1    49) 2    50) 1